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Rapid microwave assisted synthesis of nearly monodisperse aqueous CuInS₂/ZnS nanocrystals

Received 00th January 20xx, Accepted 00th January 20xx

Yatin J. Mange,^a Melissa R. Dewi,^a Thomas J. Macdonald,^{ab} William M. Skinner^a and Thomas Nann^{ac}*

DOI: 10.1039/x0xx00000x

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A rapid microwave-assisted synthesis for nearly monodisperse CuInS₂/ZnS nanocrystals (NCs) has been developed. CuInS₂/ZnS NCs have been prepared in water using thioglycolic acid as a stabilising ligand. The proposed synthesis results in stable and monodisperse NCs after only 5 minutes. In addition, the NCs were tested as potential sensitisers for photoanodes.

Semiconducting nanocrystals (NCs) may be attractive alternatives to organic dyes in sensitised photoelectrodes¹⁻⁸. They offer size-tunable optical and electronic properties, high absorption coefficients, hot electron extraction and potentially multiple exciton generation^{9–11}. Chalcopyrite copper indium disulfide (CuInS₂) NCs are of particular interest due to their low direct toxicity. band gap of 1.45eV and absorption/luminescence characteristics ranging from the ultra-violet (UV) to the near infra-red end of the electromagnetic spectrum¹². In order to improve the luminescence and stability of NCs, zinc is often introduced¹³. The introduction of zinc by cation exchange¹⁴ or shelling¹⁵ are the two most common approaches reported in the literature. Our previous work on CuInS₂/ZnS NCs investigated their cation exchange with zinc¹⁴ and more recently, their use in solar cells¹⁶. There are several routes for the synthesis of CuInS₂/ZnS NCs such as thermolysis¹⁷, photochemical deposition¹⁸ and the hot-injection method¹⁹ to achieve monodispersity. However, most of them follow an organic approach such as use of dodecanethiol as solvent, sulfur source and also as surface ligand, which renders their applicability limited due to their hydrophobic nature^{20,21}. The elimination of sterically demanding organic solvents such as octadecene (ODE), aids their chemical attachment to metal oxide surfaces such as TiO₂²² and NiO¹⁶. There are many strategies by which

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hydrophobic NCs can be made hydrophilic such as silica shell capping²³, ligand exchange^{24,25,26} and amphiphilic polymer coatings²⁷. The drawbacks of these methods include the decrease in photoluminescent quantum yield (PLQY) when NCs are transferred to water²⁸. Furthermore, the silica shell around the NCs is relatively thick introducing trapping layers, increasing the overall size of the particles and preventing access to the NC surface. All of these approaches are time consuming and controlling the reaction conditions such as temperature and growth time is often not accurate.

Microwave-assisted synthesis of NCs may have several advantages compared with conventional approaches: the method offers short reaction times, rapid and uniform heating characteristics and the resulting NCs exhibit narrow size distribution and high purity^{29,30}. In direct comparison with the hot injection method, microwave-assisted methods have distinct advantages including higher penetration of the microwave radiation resulting in homogenous heating of the material which is favorable for uniform nucleation and also formation of monodisperse NCs³¹. Another advantage of microwave-assisted synthesis is the rapid rise in temperature because of the high utilization factor of microwave energy. This results in an increase in the reaction rate by 1 to 2 orders of magnitude³². Thus, in sufficiently short time a successive epitaxial process of crystal growth occurs to form NCs, which in turn reduces the concentration of surface defects³¹. Microwave-assisted synthesis can be considered an effective strategy for making high-quality NCs. However, most of the research in this area is focused towards the synthesis of CdTe^{31,33-35} and CdSe^{30,33,36-39} NCs, a minority focuses on $CuInS_2^{40}$.

We present a quick and rapid microwave-assisted method for the synthesis of thioglycolic acid coated $CuInS_2/ZnS$ NCs via an aqueous approach. $CuInS_2/ZnS$ NCs were synthesised after 5 minutes yielding nearly monodisperse NCs, which have been characterised, by transmission electron microscopy (TEM) and dynamic light scattering (DLS). These NCs have also been

^{a.} Ian Wark Research Institute, University of South Australia, SA, Australia

^{b.} Department of Chemistry, University College London, London, United Kingdom

^c MacDiarmid Institute for Advanced Materials and Nanotechnology, School of Chemical and Physical Sciences, Victoria University of Wellington, Wellington, New Zealand. E-mail: thomas.nann@vuw.ac.nz

⁺ Electronic Supplementary Information (ESI) available: Materials, instrumentation and supplementary figures. See DOI: 10.1039/x0xx00000x

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tested for their potential use as sensitisers for water splitting or quantum dot sensitized solar cells $(QDSSCs)^{41}$.

The procedure to synthesise these NCs builds upon our previous work with some modifications¹⁴ (Materials and methods in ESI): In our synthesis 500 μ L Cu(Ac)₂ (1.25 mmol) and 500 μ L InCl₃ (1.25 mmol) were added to a flask containing 37.5 mL of deionised water (degassed) under argon at room temperature. Following this 250 μ L of a 1:5 thioglycolic acid to water aqueous solution was added as stabilising agent which caused the reaction mixture turn black and then clear again. The pH of the mixture was then adjusted to approximately 11 by adding 1 M NaOH solution. Once the pH was 11, 250 μL of aqueous Na₂S (2.5 mmol) was added causing an immediate deep orange color change. To this, 90 mg of zinc acetate was added and 6 mL of this reaction mixture was transferred into a glass vessel and placed in the microwave reactor (Discover LabMate CEM, USA). The reaction mixture was irradiated with 300 W of microwaves for 5 minutes at 90 °C. The resulting mixture had a pH of 9 and was luminescent under UV excitation, which confirms the formation of the NCs. The resulting mixture could be used as such or precipitated by adding ethanol followed by centrifugation at 15000 rpm and washing several times with ethanol. Following this, the $CuInS_2/ZnS$ powder was dried in a desiccator for 1 - 2 hours. The CuInS₂/ZnS powder thus obtained was used for further characterisation.

The photoluminescence (PL) spectra of the CuInS₂/ZnS NCs in Fig. 1 show emission around 590 nm. In Fig. 1 the broad emission band extends across the near infrared region. This feature is consistent with the emission spectra of CuInS₂/ZnS NCs synthesised by other methods^{14,21}. A small shoulder can be observed in the emission spectra in the lower energy region around 700 nm. Such a feature was attributed to the inhomogeneity of NCs⁴² and the contribution of defect sites to the overall emission⁴³. Given the direct bulk band-gap of 1.55 eV (~800nm) for CuInS₂, larger impurities might also contribute. The FWHM of the CuInS₂/ZnS NCs was found to be ~108 nm and to our knowledge this is the narrowest FWHM for aqueous CuInS₂/ZnS NCs synthesised via the microwave method. Our FWHM is also slightly narrower compared with CuInS₂/ZnS NCs synthesised via conventional method¹⁴. A small shoulder around 530 nm can be observed in the PL spectra of the core NCs (Fig. S1, ESI). The shoulder disappears upon addition of zinc, which correlates to our previous studies where the copper vacancies are being filled by zinc¹⁴. The absorption spectra for the core and CuInS₂/ZnS NCs can be found in the supporting information (Fig. S2, ESI). They exhibit a broad characteristic shoulder rather than a sharp excitonic peak mainly due to the dominance of internal and surface defects⁴³. Fig. S3 of in the ESI shows the tauc plot which was generated from the absorption spectra revealing a band gap of ~2.0 eV. This value was consistent with our previous reports of CuInS₂/ZnS NCs and further verified from the photoluminescence spectra.¹⁶ The quantum yield of the synthesised NCs was found to be approximately 1%. Due to the

low quantum yield, it was not possible to obtain an accurate measurement for the lifetime of the NCs. Future work will focus on increasing the QY of the NCs by optimizing the doping of the core-shell structures.



Fig. 1. Emission spectra of aqueous CuInS $_2$ /ZnS NCs. The purple line shows the gaussian fit for the emission curve.

Fig 2 (a-b) shows the Transmission Electron Micrographs (TEM) of the CuInS₂/ZnS NCs indicating a nearly monodisperse distribution of the particles with an average particle diameter of 5.2 \pm 1.32 nm, which was calculated from the TEM images (Fig. S4, ESI). In addition to TEM, the particle diameter was confirmed by DLS measurements, which showed the hydrodynamic diameter of the NCs (Fig. S5, ESI), the slightly larger diameters can be attributed to the TGA stabilising ligands and the solvation shell.

To confirm the CuInS₂/ZnS crystal structure, high-resolution (HR) TEM and X-Ray Diffraction (XRD) patterns have been recorded. An inter-fringe distance of 3.2 Å (Fig. 2c) has been observed by HR-TEM. This distance correlates with the (112) crystallographic plane of the NC cores and was also found in the respective XRD (Fig. 2e and Fig. S6, ESI) and selected area electron diffraction (SAED – Fig. 2d) patterns obtained during the TEM analysis. In general, the XRD pattern of the CuInS₂ core agrees well with the JCPDS file of roquesite plotted in Fig. 2e. The pattern of CuInS₂/ZnS NCs shows additional diffraction peaks, which clearly correspond with the main reflections of ZnS (cf. JCPDF data of zinc blende). Thus, this XRD pattern represents a mixture of roquesite and zinc blende, which is what we expect for the core/shell particles.

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Fig. 2. (a) TEM micrograph of CulnS₂/ZnS NCs; (b) HR-TEM of CulnS₂/ZnS NCs; (c) HR-TEM showing lattice fringes of CulnS₂/ZnS NCs to be 3.2 Å; (d) SAED of CulnS₂/ZnS NCs indicating diffraction patterns; (e) XRD patterns of CulnS₂-Core and CulnS₂/ZnS NCs and the respective JCPDS files for CulnS₂ and ZnS.

The elemental composition of CuInS₂/ZnS NCs was measured using X-Ray photoelectron spectroscopy (XPS). The S 2p spectrum for the NCs is depicted in Fig. 3. The spectrum consists of a major envelope between ~160 eV and 167 eV binding energy, and a small sulphate contribution near 168 eV. The main envelope requires four (4) S 2p doublets (2p3/2 and 2p1/2 spin orbit components) to be fitted acceptably. Contributions consistent with S-Zn and S in a CuInS₂ environment (coordinated to two Cu and two In) are located near 2p3/2 binding energies of 161.3 eV and 162.3 eV, respectively¹⁶. A strong signal typical of TGA-Cu was observed near 163.4 eV binding energy, and a final contribution appears near 164.6 eV binding energy. The latter environment has been noted for a TGA-Cu precipitate⁴⁴ and has been suggested to be a dimer (TGA₂) in that work. However it is also possible, given the sulphide substrate and the presence of sulphate, that some polysulphide may also be present. Further evidence of retained TGA ligand was found in the C 1s spectrum (inset),

also consistent with the previous TGA-Cu precipitate work⁴⁰, and the elevated carbon surface concentration.



Fig. 3. XPS spectra of S(2p) recorded from $CuInS_2/ZnS$ NCs. Inset shows the C(1s) spectra.

The NCs were tested as sensitisers for TiO_2 photoanodes. Doctor blade technique was used to coat the TiO_2 paste (see ESI for TiO_2 paste formation) onto the ITO coated glass slide followed by sintering the electrodes at 450 $^{\circ}C$ for 2 hours. CulnS₂/ZnS NCs were bound to TiO_2 by immersing TiO_2 electrodes in the CulnS₂/ZnS NC solution for 24 hours resulting in a color change from white to red. Chemical attachment of the NCs onto the TiO_2 surface was aided via the thiol and carboxyl moieties. The electrodes were then rinsed with distilled water to remove any unbound NCs.



Fig. 4. Photocurrents for TiO_2 -CuInS₂/ZnS NCs (black) and bare TiO_2 (red).

Fig. 4 shows the photocurrents of bare TiO_2 and $CuInS_2/ZnS$ NCs sensitised TiO_2 as a function of time. $CuInS_2/ZnS$ sensitised electrodes exhibited photocurrents that were higher than that of bare TiO_2 . The NCs increase the photocurrent initially but degrade rapidly. This has been previously reported and attributed to photo-oxidation of the NCs¹⁴. Altering the surface ligands and investigating different modes of chemical attachment may increase the stability. Further work on stabilising the NCs for use in energy applications is required.

In conclusion, we have developed a rapid microwave-assisted route for synthesising CuInS₂/ZnS NCs in an aqueous medium. The microwave-assisted synthesis of NCs was achieved in 5 minutes, producing nearly monodisperse particles. This work also shows that the NCs may be used in applications for sensitising wide band gap semiconductors such as TiO₂.

Notes and References

This work was performed in part at the South Australian node of the Australian National Fabrication Facility (ANFF), a company established under the National Collaborative Research Infrastructure Strategy.

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